

HBS402 THRU HBS410

Technical Data Data Sheet N2350, Rev. -



HBS402 THRU HBS410

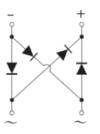
Glass Passivated Single-Phase 4.0Amp Surface Mount Bridge Rectifier



Features

- Surface mount bridge, small package;
- Ideal for printed circuit boards;
- Glass passivated chip junction;
- High surge current capability;
- High heat dissipation capability;
- Low profile package;
- Low forward voltage drop;
- Plastic package has Underwrites Laboratory Flammability Classification 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: HBS;
- Epoxy meets UL-94V-0 Flammability rating;
- Terminals:Matte tin plated leads, solderable per J-STD-002 and JESD22-B102;
- High temperature soldering guaranteed: Solder Reflow 260℃,10seconds;
- Polarity: As marked on body;
- Marking: Type number;

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

Type Number	Symbol	HBS402	HBS404	HBS406	HBS408	HBS410	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	140	280	420	560	700	V
Maximum average forward rectified output current at $@T_A = 25^{\circ}C$	I _(AV)	4				Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	130				A	
Rating for fusing (t<8.3ms)	l²t	70			A ² sec		

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Electrical Characteristics@T_A=25°C unless otherwise specified

Type Number	Symbol	HBS402	HBS404	HBS406	HBS408	HBS410	Units
Maximum Forward Voltage (per element) @I _F =1A @I _F =2A @I _F =4A	V _F	0.84 Typ. 0.89 Max. 0.88 Typ. 0.93 Max. 0.93 Typ. 0.98 Max.			V		
Maximum Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I _R	0.15 Typ. 5.0 Max. 20.0 Typ. 100 Max.			μA		
Typical capacitance(Note 1)	Cj			33			pF

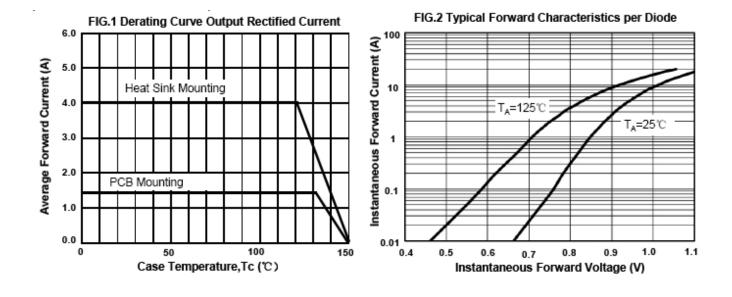
* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications@T_A=25°C unless otherwise specified

Type Number	Symbol	HBS402	HBS404	HBS406	HBS408	HBS410	Units
Typical Thermal Resistance	R _{0JA} R0JC R0JL	67.0 7.0 11.0			°C/W		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150			°C		

Note: 1. Mounted at 1.0 MHz and applied reverse voltage of 5.0V DC.

Ratings and Characteristics Curves

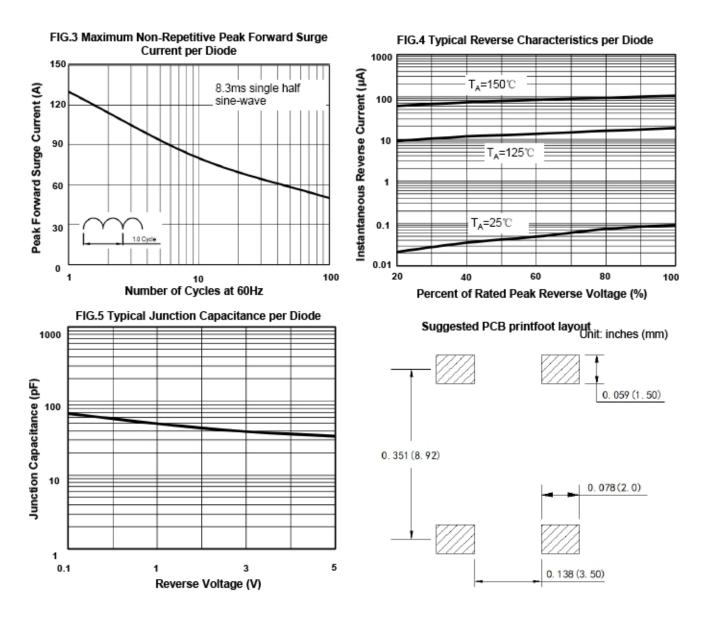


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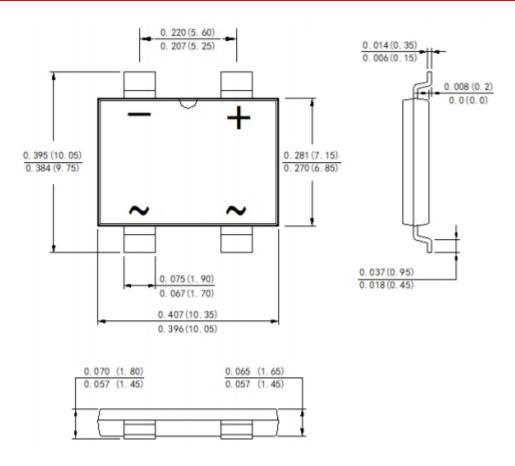








Mechanical Dimensions HBS(Inches/Millimeters)

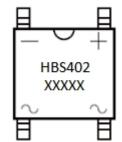


Ordering Information

Device	Package	Plating	Shipping
HBS402 THRU HBS410	HBS (Pb-Free)	Pure Sn	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

- HBS402 = Type Number YΥ
 - = Year

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- = Week = Lot Number
- Cautions: Molding resin Epoxy resin UL:94V-0

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THRU **HBS410**

HBS402

RoHS Pb







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